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UNITED STATES PATENT AND TRADEMARK OFFICE  
**CERTIFICATE OF CORRECTION**

PATENT NO. : 6,787,861 B2  
DATED : September 7, 2004  
INVENTOR(S) : Lucovsky et al.

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It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 12.

Line 4, should read -- **15**. The field effect transistor according to claim 3, --  
Line 9, should read -- **16**. The field effect transistor according to claim 3, --  
Line 13, should read -- **17**. The field effect transistor according to claim 3, --

Signed and Sealed this

First Day of February, 2005



JON W. DUDAS  
*Director of the United States Patent and Trademark Office*